

Hex Inverting Schmitt Trigger

CD40106

Logic

1 Introduction

The CD40106 provides six inverting buffers. Each input has a Schmitt trigger circuit. The inverting buffer switches at different points for positive-going and negative-going signals. The difference between the positive voltage (V_{T+}) and the negative voltage (V_{T-}) is defined as hysteresis voltage (V_H).

The CD40106 may be used for enhanced noise immunity or to “square up” slowly changing waveforms.

It operates over a recommended V_{DD} power supply range of 3V to 15V referenced to V_{SS} (usually ground). Unused inputs must be connected to V_{DD} , V_{SS} , or another input.

2 Available Packages

PART NUMBER	PACKAGE
CD40106	SOP14
	TSSOP14

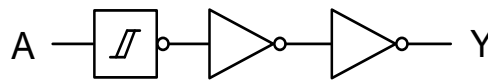
Note: For all available packages, please refer to the part Orderable Information.

3 Features

- Wide supply voltage range from 3V to 15V
- Schmitt trigger input discrimination
- Fully static operation
- 5V, 10V, and 15V parametric ratings
- Standardized symmetrical output characteristics
- Specified from -40°C to +125°C

4 Applications

- Wave and Pulse Shapers
- High-Noise-Environment Systems
- Monostable Multivibrators
- Astable Multivibrators



Logic diagram

5 Orderable Information

DEVICE	PACKAGE	OP TEMP	ECO PLAN	MSL	PACKING OPTION	SORT
CD40106ADN	SOP14	-40~125°C	RoHS & Green	Level 3 168HR	Tape and Reel 4000 Units / Reel	Active
CD40106BDN	TSSOP14	-40~125°C	RoHS & Green	Level 3 168HR	Tape and Reel 5000 Units / Reel	Active

Note:

ECO PLAN: For the RoHS and Green certification standards of this product, please refer to the official report provided by JSCJ.

MSL: Moisture Sensitivity Level. Determined according to JEDEC industry standard classification.

SORT: Specifically defined as follows:

Active: Recommended for new products;

Customized: Products manufactured to meet the specific needs of customers;

Preview: The device has been released and has not been fully mass produced. The sample may or may not be available;

NoRD: It is not recommended to use the device for new design. The device is only produced for the needs of existing customers;

Obsolete: The device has been discontinued.

6 Pin Configuration and Marking Information

6.1 Pin Configuration

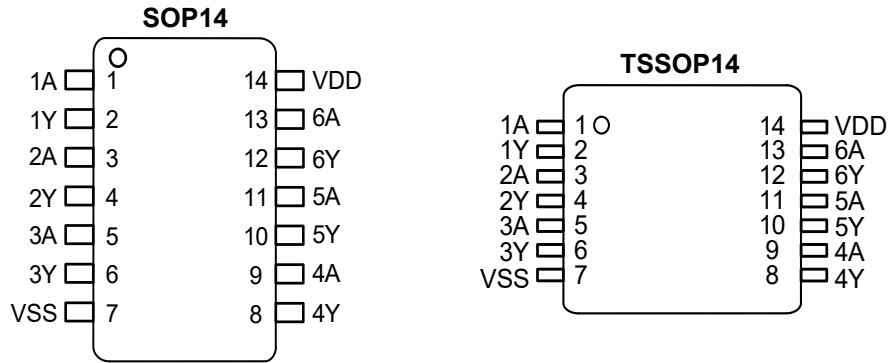


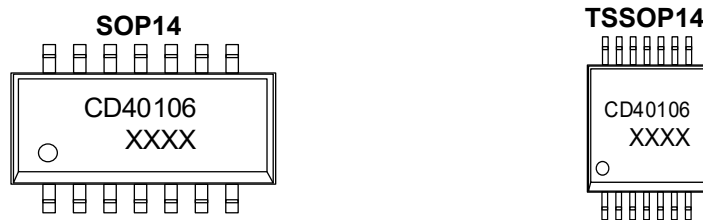
Figure 6-1 Pin configuration

6.2 Pin Function

PIN		I/O ⁽¹⁾	DESCRIPTION
No.	NAME		
1	1A	I	Data input
2	1Y	O	Data output
3	2A	I	Data input
4	2Y	O	Data output
5	3A	I	Data input
6	3Y	O	Data output
7	VSS	G	Ground (0V)
8	4Y	O	Data output
9	4A	I	Data input
10	5Y	O	Data output
11	5A	I	Data input
12	6Y	O	Data output
13	6A	I	Data input
14	VDD	P	Supply voltage

(1) I-Input, O-Output, P-Power, G-Ground

6.3 Marking Information



XXXX: Code, indicates weekly record information.

7 Specifications

7.1 Absolute Maximum Ratings

Voltages are referenced to V_{SS} (ground=0V), unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS		MIN.	MAX.	UNIT
V_{DD}	Supply voltage	-		-0.5	+18	V
I_{IK}	DC input current	Any one input		-	± 10	mA
V_I	Input voltage	All inputs		-0.5	$V_{DD}+0.5$	V
T_{stg}	Storage temperature	-		-65	+150	°C
P_{tot}	Total power dissipation	-		-	500	mW
P	Device dissipation	Per output transistor		-	100	mW
T_L	Soldering temperature	10s	SOP/TSSOP	-	260	°C

Note: Absolute maximum ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are absolute voltages referenced to GND. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions.

7.2 Recommended Operating Conditions

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_{DD}	Supply voltage	-	3	-	15	V
T_{amb}	Ambient temperature	In free air	-40	-	+125	°C

7.3 Electrical Characteristics
7.3.1 DC Characteristics 1

$T_{amb}=25^{\circ}\text{C}$, voltages are referenced to V_{SS} (ground=0V), unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS			$T_{amb}=25^{\circ}\text{C}$			UNIT
		V_O	V_{IN}	V_{DD}	MIN.	TYP.	MAX.	
I_{DD}	Supply current	-	0/5	5	-	-	1	μA
		-	0/10	10	-	-	2	μA
		-	0/15	15	-	-	4	μA
I_{OL}	LOW-level output current	0.4	0/5	5	0.51	1	-	mA
		0.5	0/10	10	1.3	2.6	-	mA
		1.5	0/15	15	3.4	6.8	-	mA
I_{OH}	HIGH-level output current	4.6	0/5	5	-0.51	-	-	mA
		2.5	0/5	5	-1.6	-	-	mA
		9.5	0/10	10	-1.3	-	-	mA
		13.5	0/15	15	-3.4	-	-	mA
V_{OL}	LOW-level output voltage	-	5	5	-	0	0.05	V
		-	10	10	-	0	0.05	V
		-	15	15	-	0	0.05	V
V_{OH}	HIGH-level output voltage	-	0	5	4.95	5	-	V
		-	0	10	9.95	10	-	V
		-	0	15	14.95	15	-	V
I_I	Input leakage current	-	0/15	15	-	-	± 1	μA

7.3.2 DC Characteristics 2

T_{amb}=-40°C to +125°C, voltages are referenced to V_{SS} (ground=0V), unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS			T _{amb} =-40°C		T _{amb} =+85°C		T _{amb} =+125°C		UNIT
		V _O	V _{IN}	V _{DD}	MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
I _{DD}	Supply current	-	0/5	5	-	1	-	30	-	30	uA
		-	0/10	10	-	2	-	60	-	60	uA
		-	0/15	15	-	4	-	120	-	120	uA
I _{OL}	LOW-level output current	0.4	0/5	5	0.61	-	0.42	-	0.36	-	mA
		0.5	0/10	10	1.5	-	1.1	-	0.9	-	mA
		1.5	0/15	15	4	-	2.8	-	2.4	-	mA
I _{OH}	HIGH-level output current	4.6	0/5	5	-0.61	-	-0.42	-	-0.36	-	mA
		2.5	0/5	5	-1.8	-	-1.3	-	-1.15	-	mA
		9.5	0/10	10	-1.5	-	-1.1	-	-0.9	-	mA
		13.5	0/15	15	-4	-	-2.8	-	-2.4	-	mA
V _{OL}	LOW-level output voltage	-	5	5	-	0.05	-	0.05	-	0.05	V
		-	10	10	-	0.05	-	0.05	-	0.05	V
		-	15	15	-	0.05	-	0.05	-	0.05	V
V _{OH}	HIGH-level output voltage	-	0	5	4.95	-	4.95	-	4.95	-	V
		-	0	10	9.95	-	9.95	-	9.95	-	V
		-	0	15	14.95	-	14.95	-	14.95	-	V
I _I	Input leakage current	-	0/15	15	-	±1	-	±1	-	±1	uA

7.3.3 AC Characteristics

T_{amb}=25°C, V_{SS}=0V, t_r, t_f=20ns, C_L=50pF, R_L=200kΩ, unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT	
t _{PHL} , t _{PLH}	Propagation delay time	See Figure 8-4	V _{DD} =5V	-	140	280	ns
		See Figure 8-4	V _{DD} =10V	-	70	140	ns
			V _{DD} =15V	-	60	120	ns
t _{THL} , t _{TLH}	Transition time	See Figure 8-4	V _{DD} =5V	-	100	200	ns
			V _{DD} =10V	-	50	100	ns
			V _{DD} =15V	-	40	80	ns
C _I	Input capacitance	Any input	-	5	7.5	pF	

7.3.4 Transfer Characteristics 1

T_{amb}=25°C, voltages are referenced to V_{SS} (ground=0V), unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS			T _{amb} =25°C			UNIT
		V _O	V _{IN}	V _{DD}	MIN.	TYP.	MAX.	
V _{T+}	Positive-going threshold voltage	-	-	5	2.2	2.9	3.6	V
		-	-	10	4.6	5.9	7.1	V
		-	-	15	6.8	8.8	10.8	V
V _{T-}	Negative-going threshold voltage	-	-	5	0.9	1.9	2.8	V
		-	-	10	2.5	3.9	5.2	V
		-	-	15	4	5.8	7.4	V
V _H	Hysteresis voltage	-	-	5	0.3	0.9	1.6	V
		-	-	10	1.2	2.3	3.4	V
		-	-	15	1.6	3.5	5	V

Note: See figure 8-5 and figure 8-6.

7.3.5 Transfer Characteristics 2

T_{amb}=-40°C to +125°C, voltages are referenced to GND (ground = 0V), unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS			T _{amb} =-40°C		T _{amb} =+85°C		T _{amb} =+125°C		UNIT
		V _O	V _{IN}	V _{DD}	MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
V _{T+}	Positive-going threshold voltage	-	-	5	2.2	3.6	2.2	3.6	2.2	3.6	V
		-	-	10	4.6	7.1	4.6	7.1	4.6	7.1	V
		-	-	15	6.8	10.8	6.8	10.8	6.8	10.8	V
V _{T-}	Negative-going threshold voltage	-	-	5	0.9	2.8	0.9	2.8	0.9	2.8	V
		-	-	10	2.5	5.2	2.5	5.2	2.5	5.2	V
		-	-	15	4	7.4	4	7.4	4	7.4	V
V _H	Hysteresis voltage	-	-	5	0.3	1.6	0.3	1.6	0.3	1.6	V
		-	-	10	1.2	3.4	1.2	3.4	1.2	3.4	V
		-	-	15	1.6	5	1.6	5	1.6	5	V

Note: See figure 8-5 and figure 8-6.

8 Detailed Description

8.1 Overview

The CD40106 provides six inverting buffers. Each input has a Schmitt trigger circuit. The inverting buffer switches at different points for positive-going and negative-going signals. The difference between the positive voltage (V_{T+}) and the negative voltage (V_{T-}) is defined as hysteresis voltage (V_H).

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8.2 Functional Block Diagram

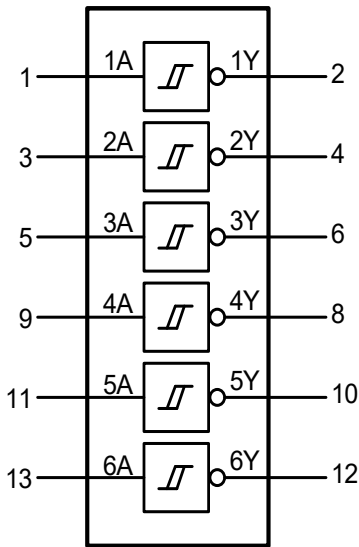


Figure 8-1 Functional diagram

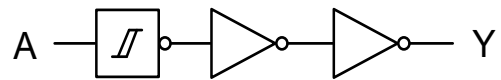


Figure 8-2 Logic diagram (one inverting buffer)

8.3 Function Table

INPUT	OUTPUT
nA	nY
L	H
H	L

Note: H=HIGH voltage level; L=LOW voltage level.

8.4 Testing Circuit

8.4.1 AC Testing Circuit

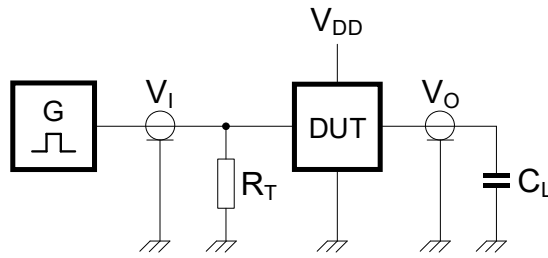


Figure 8-3 Test circuit for switching times

Definitions for test circuit:

DUT=Device Under Test.

C_L =Load capacitance including jig and probe capacitance.

R_T =Termination resistance should be equal to the output impedance Z_o of the pulse generator.

8.4.2 AC Testing Waveforms

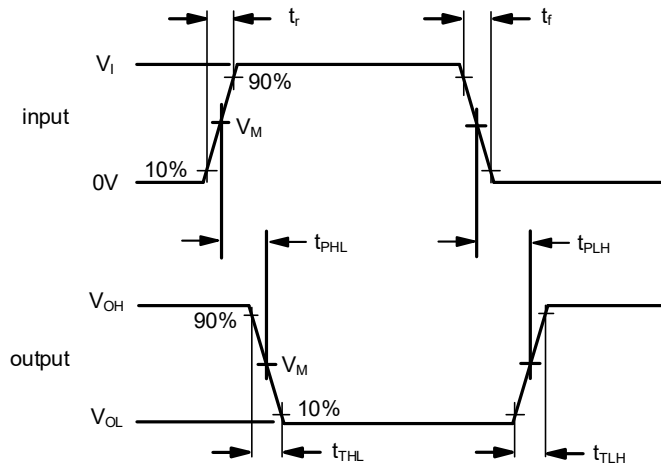


Figure 8-4 Propagation delay and output transition time

8.4.3 Transfer Characteristics Waveforms

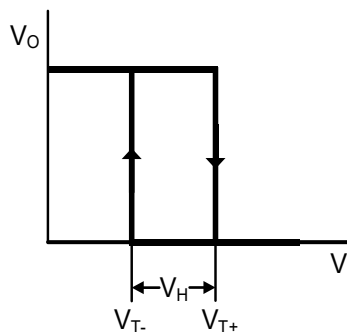


Figure 8-5 Transfer characteristic

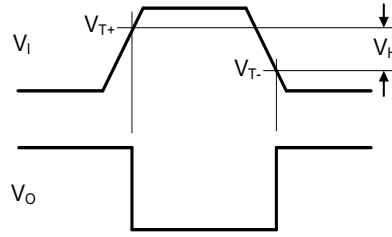


Figure 8-6 Waveforms showing definition of V_{T+} and V_{T-} (between limits at 30% and 70%) and V_H

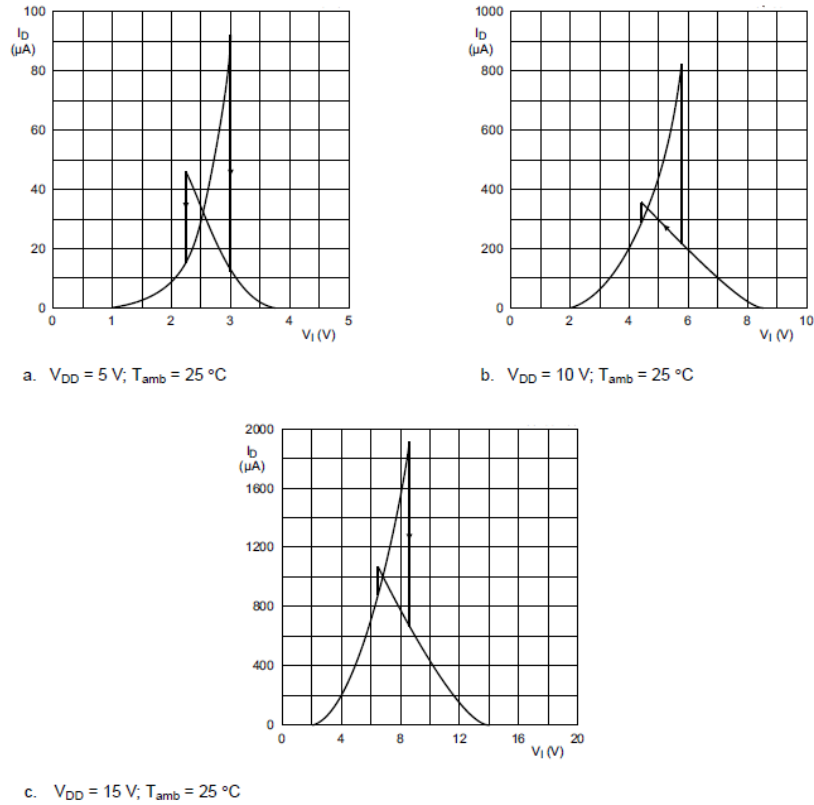


Figure 8-7 Typical drain current as a function of input

8.4.4 Measurement Points

SUPPLY VOLTAGE	INPUT	OUTPUT
V_{DD}	V_M	V_M
5V to 15V	$0.5 \times V_{DD}$	$0.5 \times V_{DD}$

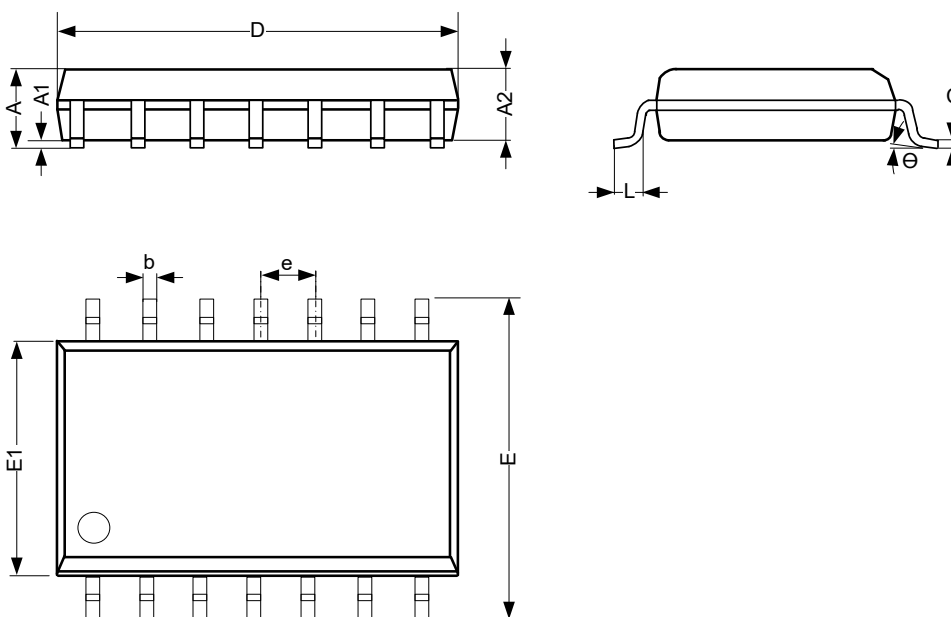
8.4.5 Test Data

SUPPLY VOLTAGE	INPUT		LOAD
V_{DD}	V_I	t_r, t_f	C_L
5V to 15V	V_{SS} or V_{DD}	$\leq 20\text{ ns}$	50pF

9 Mechanical Information

9.1 SOP14 Mechanical Information

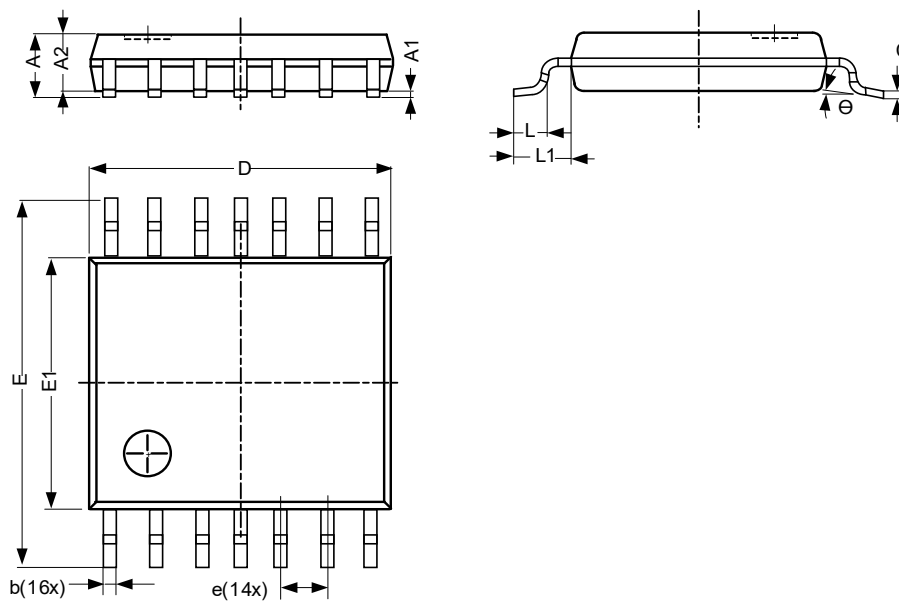
9.1.1 SOP14 Outline Dimensions



SYMBOL	Dimensions In Millimeters		
	Min.	Typ.	Max.
A	1.50	-	1.75
A1	0.05	-	0.25
A2	1.30	-	-
b	0.33	-	0.50
c	0.19	-	0.25
D	8.43	-	8.76
E	5.80	-	6.25
E1	3.75	-	4.00
e	1.27 BSC		
L	0.40	-	0.89
θ	0°	-	8°
Unit: mm			

9.2 TSSOP14 Mechanical Information

9.2.1 TSSOP14 Outline Dimensions



SYMBOL	Dimensions In Millimeters		
	Min.	Typ.	Max.
A	-	-	1.20
A1	0.05	-	0.15
A2	0.80	-	1.05
b	0.19	-	0.30
c	0.09	-	0.20
D	4.90	-	5.10
E	6.20	-	6.60
E1	4.30	-	4.50
e	0.65 BSC		
L	0.45	-	0.75
L1	-	1.00	-
Θ	0°	-	8°
Unit: mm			

10 Notes and Revision History

10.1 Associated Product Family and Others

To view other products of the same type or IC products of other types, click the official website of JSCJ -- <https://www.jscj-elec.com> for more details.

10.2 Notes

Electrostatic Discharge Caution



This IC may be damaged by ESD. Relevant personnel shall comply with correct installation and use specifications to avoid ESD damage to the IC. If appropriate measures are not taken to prevent ESD damage, the hazards caused by ESD include but are not limited to degradation of integrated circuit performance or complete damage of integrated circuit. For some precision integrated circuits, a very small parameter change may cause the whole device to be inconsistent with its published specifications.

DISCLAIMER

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